

30 V, N-channel Trench MOSFET 16 March 2016

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic level compatible
- Low on-state resistance
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 1 kV HBM
- Enhanced power dissipation capability of 1 W

3. Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

4. Quick reference data

| Table 1. Quie | ck reference data | | | | | | |
|------------------------|----------------------------------|------------------------------------------------------------------------|-----|-----|-----|-----|------|
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
| V _{DS} | drain-source voltage | T _j = 25 °C | | - | - | 30 | V |
| V _{GS} | gate-source voltage | - | | -20 | - | 20 | V |
| I _D | drain current | V_{GS} = 10 V; T_{amb} = 25 °C; t ≤ 5 s | [1] | - | - | 5.1 | А |
| Static characteristics | | | | | | | |
| R _{DSon} | drain-source on-state resistance | V _{GS} = 10 V; I _D = 4.4 A; T _j = 25 °C | | - | 29 | 36 | mΩ |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².



5. Pinning information

| Table 2. | Pinning | information | | |
|----------|---------|-------------|-------------------------|--------------------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | G | gate | 3 | D |
| 2 | S | source | | |
| 3 | D | drain | 1 2 TO-236AB (SOT23) | G G S 017aaa255 |

6. Ordering information

| Table 3. Ordering information | | | | | | | |
|-------------------------------|----------|------------------------------------------|---------|--|--|--|--|
| Type number | Package | | | | | | |
| | Name | Description | Version | | | | |
| PMV42ENE | TO-236AB | plastic surface-mounted package; 3 leads | SOT23 | | | | |

7. Marking

| Table 4. Marking codes | |
|------------------------|--------------|
| Type number | Marking code |
| | [1] |
| PMV42ENE | BL% |

[1] % = placeholder for manufacturing site code

8. Limiting values

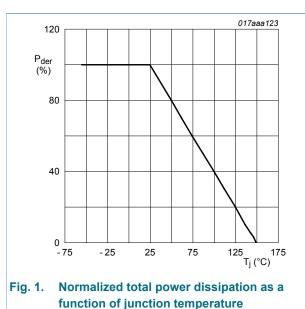
Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|-------------------------|-------------------------------------------------------|-----|-----|------|------|
| V _{DS} | drain-source voltage | T _j = 25 °C | | - | 30 | V |
| V _{GS} | gate-source voltage | | | -20 | 20 | V |
| I _D | drain current | V_{GS} = 10 V; T_{amb} = 25 °C; t ≤ 5 s | [1] | - | 5.1 | А |
| | | V _{GS} = 10 V; T _{amb} = 25 °C | [1] | - | 4.4 | А |
| | | V _{GS} = 10 V; T _{amb} = 100 °C | [1] | - | 2.7 | А |
| I _{DM} | peak drain current | T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$ | | - | 18 | А |
| P _{tot} | total power dissipation | T _{amb} = 25 °C | [2] | - | 500 | mW |
| | | | [1] | - | 1.04 | W |
| | | T _{sp} = 25 °C | | - | 5 | W |
| Tj | junction temperature | | | -55 | 150 | °C |
| T _{amb} | ambient temperature | | | -55 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |
| Source-dra | in diode | | | | | |
| I _S | source current | T _{amb} = 25 °C | [1] | - | 1 | А |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



 $P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$

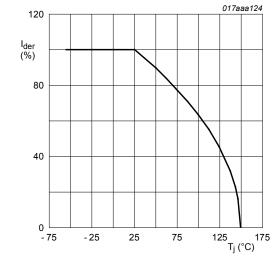


Fig. 2. Normalized continuous drain current as a function of junction temperature

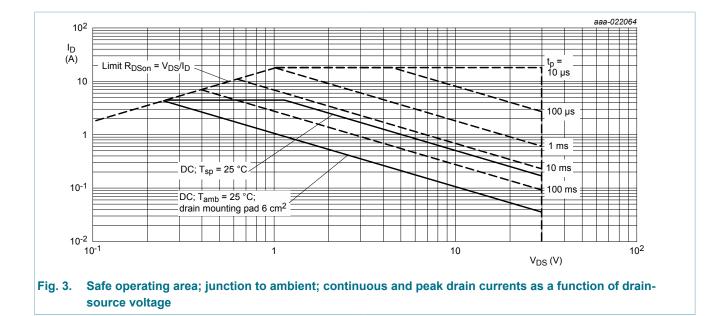
$$I_{der} = \frac{I_D}{I_D(25^{\circ}C)} \times 100 \%$$

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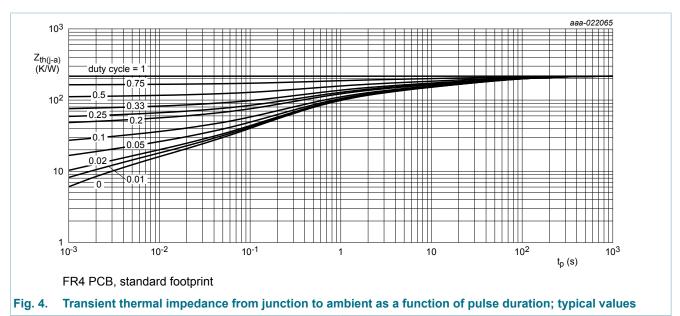


9. Thermal characteristics

| Table 6. Thermal characteristics | | | | | | | |
|----------------------------------|--------------------------------------------------------|--------------------------|-------------|-----|-----|-----|------|
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | [1] | - | 218 | 250 | K/W |
| | | | [<u>2]</u> | - | 105 | 120 | K/W |
| | | in free air; $t \le 5 s$ | [2] | - | 72 | 83 | K/W |
| R _{th(j-sp)} | thermal resistance from junction to solder point | | | - | 20 | 25 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².



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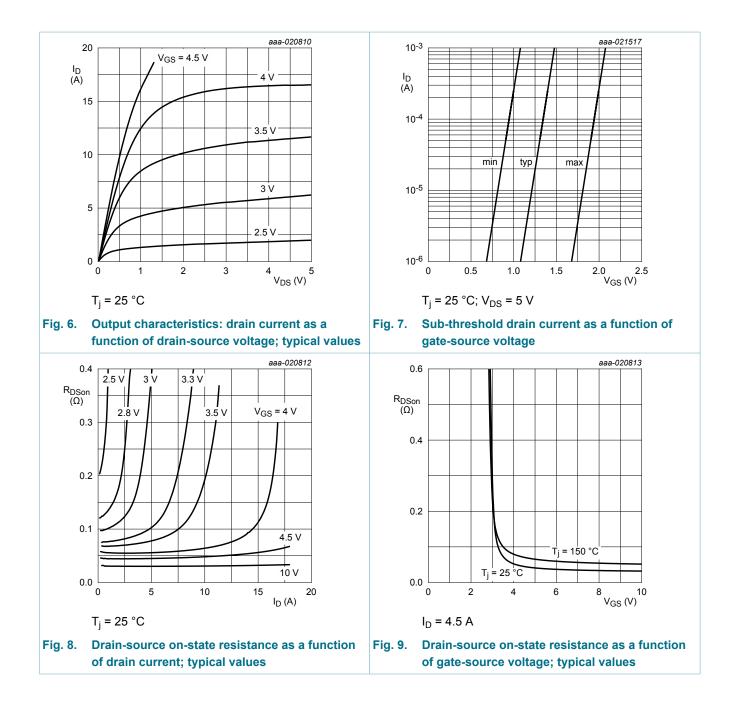


10. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|-----------------------------------|------------------------------------------------------------------------|-----|-----|------|------|
| Static chara | octeristics | | | | | |
| V _{(BR)DSS} | drain-source breakdown voltage | I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C | 30 | - | - | V |
| V _{GSth} | gate-source threshold voltage | I_D = 250 µA; V_{DS} = V_{GS} ; T_j = 25 °C | 1 | 1.4 | 2 | V |
| I _{DSS} | drain leakage current | V_{DS} = 30 V; V_{GS} = 0 V; T_j = 25 °C | - | - | 1 | μA |
| I _{GSS} | gate leakage current | V_{GS} = 16 V; V_{DS} = 0 V; T_j = 25 °C | - | - | 10 | μA |
| | | V_{GS} = -16 V; V_{DS} = 0 V; T_j = 25 °C | - | - | -10 | μA |
| | | V_{GS} = 4.5 V; V_{DS} = 0 V; T_j = 25 °C | - | - | 100 | nA |
| | | V_{GS} = -4.5 V; V_{DS} = 0 V; T_j = 25 °C | - | - | -100 | nA |
| R _{DSon} | drain-source on-state | V _{GS} = 10 V; I _D = 4.4 A; T _j = 25 °C | - | 29 | 36 | mΩ |
| resistance | resistance | V_{GS} = 10 V; I _D = 4.4 A; T _j = 150 °C | - | 46 | 57 | mΩ |
| | | V_{GS} = 4.5 V; I _D = 3.5 A; T _j = 25 °C | - | 42 | 54 | mΩ |
| 9 _{fs} | forward transconductance | V_{DS} = 10 V; I _D = 4.4 A; T _j = 25 °C | - | 7 | - | S |
| R _G | gate resistance | f = 1 MHz; T _j = 25 °C | - | 1.5 | - | Ω |
| Dynamic ch | aracteristics | | | | | |
| Q _{G(tot)} | total gate charge | V_{DS} = 15 V; I _D = 4.4 A; V _{GS} = 10 V; | - | 5.5 | 9 | nC |
| Q _{GS} | gate-source charge | T _j = 25 °C | - | 0.8 | - | nC |
| Q _{GD} | gate-drain charge | _ | - | 1.1 | - | nC |
| C _{iss} | input capacitance | V_{DS} = 15 V; f = 1 MHz; V_{GS} = 0 V; | - | 281 | - | pF |
| C _{oss} | output capacitance | T _j = 25 °C | - | 42 | - | pF |
| C _{rss} | reverse transfer capacitance | | - | 32 | - | pF |
| t _{d(on)} | turn-on delay time | V_{DS} = 15 V; I _D = 4.4 A; V _{GS} = 10 V; | - | 5 | - | ns |
| t _r | rise time | R _{G(ext)} = 6 Ω; T _j = 25 °C | - | 18 | - | ns |
| t _{d(off)} | turn-off delay time | | - | 9 | - | ns |
| t _f | fall time | | - | 3 | - | ns |
| Source-drai | n diode | | | | 1 | |
| V _{SD} | source-drain voltage | I _S = 1 A; V _{GS} = 0 V; T _i = 25 °C | - | 0.8 | 1.2 | V |

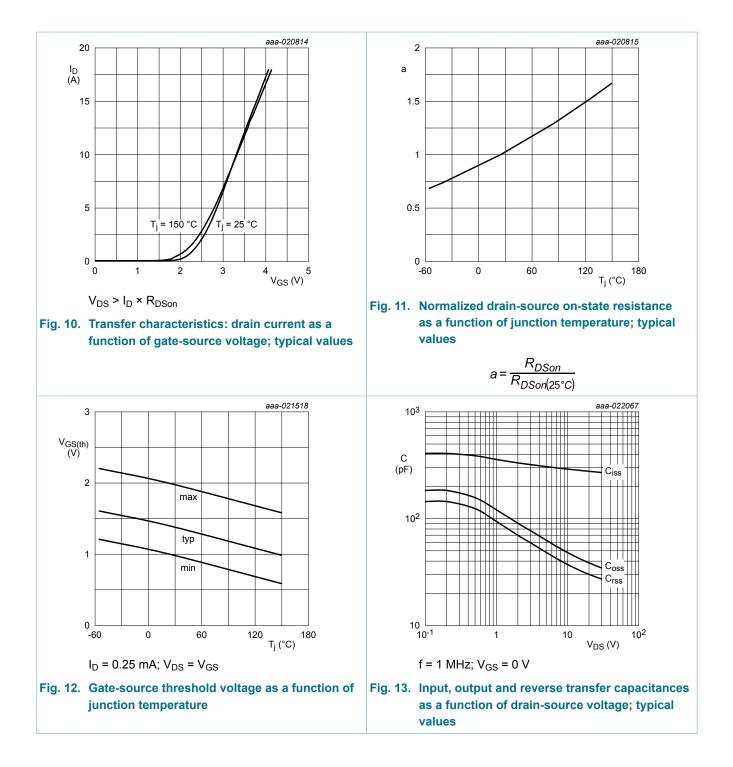
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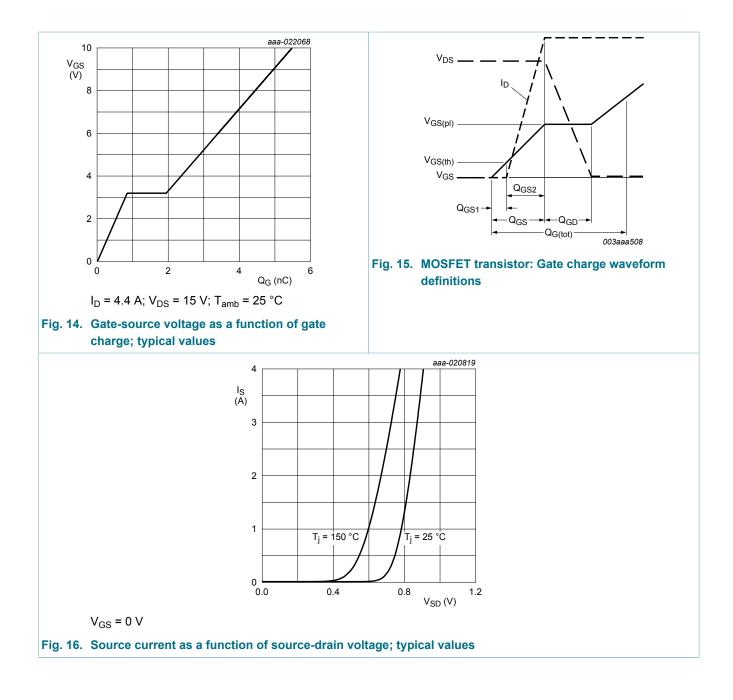
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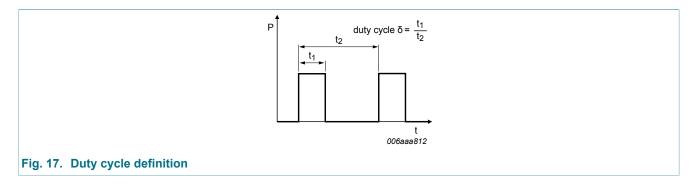
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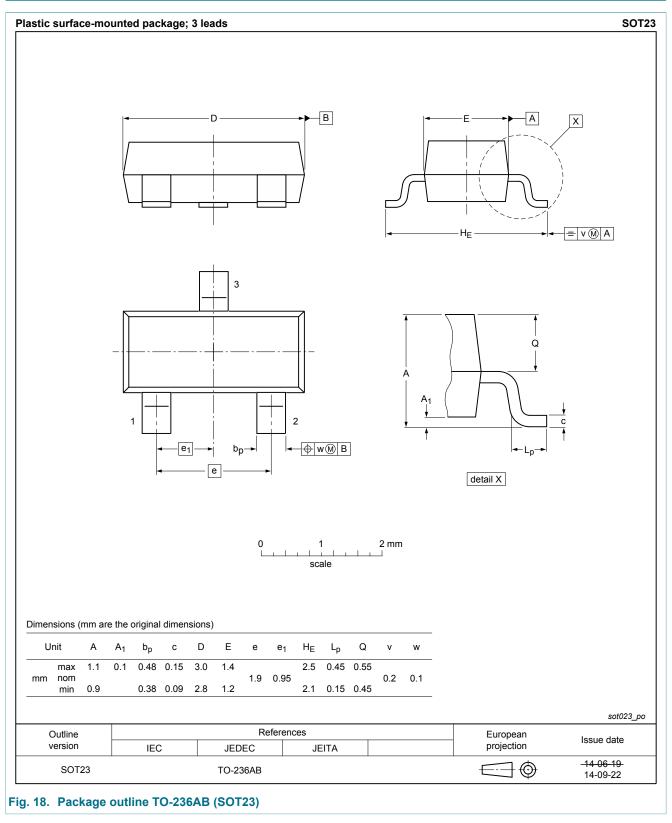


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11. Test information

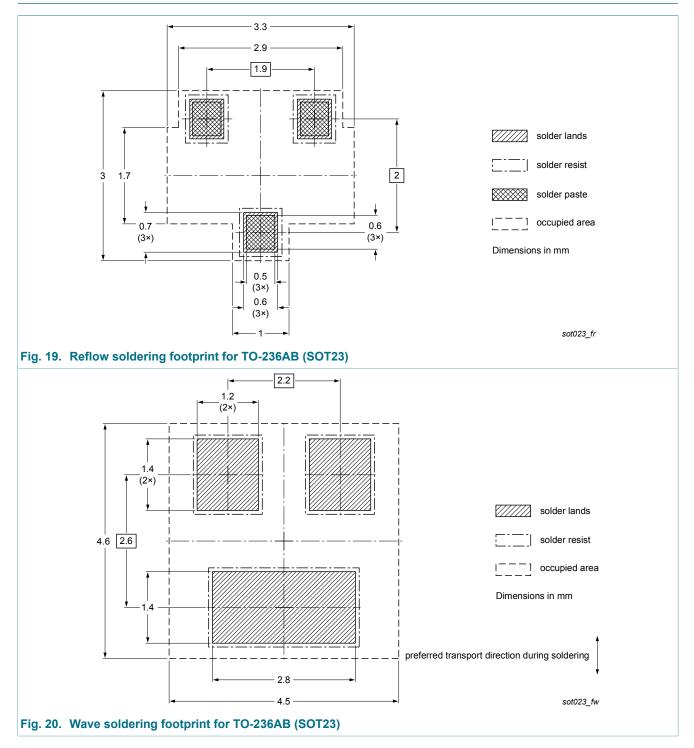


12. Package outline



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13. Soldering



14. Revision history

| Table 8. Revision his | Table 8. Revision history | | | | | | |
|-----------------------|---------------------------|--------------------|---------------|------------|--|--|--|
| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes | | | |
| PMV42ENE v.1 | 20160316 | Product data sheet | - | - | | | |

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15. Legal information

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| Document status [1][2] | Product status [3] | Definition |
|--------------------------------------|-----------------------|---------------------------------------------------------------------------------------------|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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